Synthesis, Crystal and Electronic Structures, Linear and Nonlinear Optical Properties, and Photocurrent Response of Oxyhalides CeHaVIO₄ (Ha=Cl, Br; VI=Mo, W)

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Abstract

Four heteroanionic oxyhalides, CeClMoO₄, CeBrMoO₄, CeClWO₄, and CeBrWO₄, have been studied as multifunctional materials, which combine good second harmonic generation (SHG) response and photocurrent signals. Millimeter-sized CeHaVIO₄ (Ha=Cl, Br; VI=Mo, W) crystals were grown by halide salt flux. The crystal structure of CeHaVIO₄ crystals was accurately determined by single crystal X-ray diffraction. CeClMoO₄, CeBrMoO₄, and CeBrWO₄ are isostructural to each other, which crystallize in the acentric LaBrMoO₄ structure type. CeClWO₄ crystallizes in a new structure type with unit cell parameters of a=19.6059(2) Å, b=5.89450(10) Å, c=7.80090(10) Å, β =101.4746(8)°. The bandgaps of CeHaVIO₄ fall into the range of 2.8(1)-3.1(1) eV, which are much smaller than the isotypic LaHaVIO₄ (Ha=Cl, Br; VI=Mo, W) of 3.9(1)-4.3(1) eV. The narrowing of bandgaps in CeHaVIO₄ originates from the presence of partially filled 4f orbitals of cerium atoms, which was confirmed by density functional theory (DFT) calculations. The moderate bandgaps make CeHaVIO₄ suitable for infrared nonlinear optical applications (IR NLO). CeBrMoO₄ and CeBrWO₄ exhibit moderate SHG responses of 0.58× AGS and 0.46× AGS, respectively, which are both type-I phase-matching materials. Moderate SHG response, easygrowth of crystals, high ambient stability, and type-I phase-matching behavior set CeBrMoO4 and CeBrWO₄ as great materials for IR NLO applications. CeHaVIO₄ films also exhibited good

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photocurrent response upon light radiation. This work demonstrates the rich structure chemistry of the REHaVIO₄ (RE=Y, La-Lu, Ha=Cl, Br; VI=Mo, W) family and the potential presence of more multifunctional materials.

Introduction

Infrared nonlinear optical (IR NLO) materials have been vigorously studied due to their irreplaceable roles in solid-state lasers, which are utilized to expand infrared laser frequency via the second harmonic generation process ¹⁻¹⁴. The options for IR NLO materials are still limited to a few commercial materials such as ZnGeP2, AgGaS2, and AgGaSe2. These commercial materials cannot be utilized to cover the full spectrum range of 3-25 µm due to intrinsic limitations such as low laser damage thresholds (AgGaS₂, and AgGaSe₂) ¹⁵ and double-photon absorption (ZnGeP₂) ¹⁶. A state-of-the-art IR NLO material should crystallize in an acentric structure and, ideally, balance a large second harmonic generation coefficient (SHG, d_{ij} >AgGaS₂), moderate birefringence (Δn) for phase matchability, high laser damage threshold (LDT, >AgGaS₂), large bandgap for good transmission range (>3.5 eV) and good thermal-, air-, and chemical stability, all of which are nearly impossible for many systems. Balancing these properties to satisfy these criteria is not a simple task due to the fact that many of these parameters are intrinsically correlated ¹⁷⁻²⁹. For example, in general, a material with a large bandgap should have a high LDT, but the SHG coefficients would be expected to be low. Inversely, small bandgap materials are more likely to have large SHG coefficients, but with the price of sacrificing LDT ^{17, 21, 29-31}. Hence, finding a chemical system, which meets all criteria, is important and challenging.

Oxyhalides, which constitute two anions of oxygen and halogen, have been emerging as important NLO materials, especially for covering visible or ultraviolet spectrum range, but rarely used for IR NLO applications ³²⁻⁴². There are two major reasons for this: first, the presence of metal-oxygen bonds, whose intrinsic vibrations are over the spectrum ranges of 3-5 μm and 8-12 μm, resulting in high optical absorption of desired IR spectrum range; second, the strong ionic metal-halogen interactions, which have tight bonding of valence electrons around anions, generating very large bandgaps ³²⁻⁴². A very large bandgap is usually accompanied by a small SHG response. Hence, a good strategy to "push" oxyhalides into the IR spectrum range is necessary. One successful strategy to create good oxyhalide IR NLO materials is to incorporate heavy metals like Pb, such as, Pb₁₇O₈Cl₁₈ ⁴³, Pb₁₃O₆Cl₄Br₁₀ ⁴⁴, Pb₁₈O₈Cl₁₅I₅ ⁴⁵. Another good method to employ oxyhalides as

IR NLO materials is to add more anions such as [Ba₂F₂][Ge₂O₃S₂] ⁴⁶. All these strategies have successfully suppressed the bandgaps of inorganic solids, leading to good transmission over the IR spectrum range while maintaining high SHG responses. In this work, we attempted a new strategy of utilizing Ce's partially occupied 4*f* orbitals to narrow the bandgaps of oxyhalides CeHaVIO₄ into the IR spectrum range and succeeded. For instance, CeBrWO₄ is isostructural to LaBrWO₄. By replacing La by Ce, the bandgap was narrowed from 4.2(1) eV to 2.8(1) eV for LaBrWO₄ and CeBrWO₄, respectively. The synthesis, crystal and electronic structures, and linear and nonlinear optical properties of oxyhalides CeHaVIO₄ (Ha=Cl, Br; VI=Mo, W) are reported in this work. CeBrMoO₄ is found to be a good IR NLO material with balanced properties (E_g=3.0(1) eV, SHG: 0.58× AGS). Therefore, this work finds a new method to modulate oxyhalides as potential IR NLO materials.

Experimental Details

Synthesis and crystal growth: Raw reactants in this work were used as received without further processing: CeBr₃ (Thermo Fisher Scientific, 99.9%), CeCl₃ (Thermo Fisher Scientific, 99.9%), Ce₂O₃ (MSE Supplies, 99.9%), MoO₃ (Alfa Aesar, 99.5 %), WO₃ (Alfa Aesar, 99.8%), NaBr (Thermo Fisher Scientific, 99+%), NaCl (Sigma-Aldrich, anhydrous, 99.5%). All these reactants were stored in an argon-filled glovebox and the moisture and oxygen levels of the glovebox were kept below 0.5 ppm.

CecIVIO₄ (VI=Mo, W): Flux CeCl₃/NaCl was utilized to grow crystals of CeClVIO₄ (VI=Mo, W). 0.4 g of CeCl₃, Ce₂O₃, and VIO₃ (VI=Mo, W) mixed in a molar ratio of 1:1:3 were loaded into a carbonized silica tube first. Then, 0.4 g of flux of CeCl₃/NaCl mixed in a molar ratio of 1:2 were loaded to cover the top of reactants. The silica tubes were transferred out of glovebox and sealed by a torch under a vacuum of 10⁻² Torr. The tube was heated from room temperature to 820 °C in 10 hrs and held for 168 hrs before naturally cooling down. The crystals were collected after the flux was removed by DI water. **CeBrVIO**₄ (VI=Mo, W): A similar synthetic routine was employed with CeBr₃/NaBr=1:2 as flux. 0.4 g reactants of CeBr₃, Ce₂O₃, and VIO₃ (VI=Mo, W) mixed in a molar ratio of 1:1:3 were covered by 0.4 g flux. The temperature profile of CeBrVIO₄ (VI=Mo, W) was identical to CeClVIO₄ (VI=Mo, W). The crystals were collected after the flux was washed away by DI water. The optical microscope photos of crystals of CeHaVIO₄ (Ha=Cl, Br; VI=Mo, W) are shown in **Figure S1**. All samples in this work are stable in air for a long time.

The mixed-cation compounds of (La_{0.5}Ce_{0.5}) HaVIO₄ (Ha=Cl, Br; VI=Mo, W) were grown by using the following equations: 3(La_{0.5}Ce_{0.5})HaVIO₄=0.5LaHa₃+0.5CeHa₃+0.5Ce₂O₃+0.5La₂O₃+3VIO₃ with flux of CeHa₃/LaHa₃/NaHa=0.5:0.5:2, where Ha=Cl, Br and VI=Mo, W. The temperature profile of mixed-cation compounds was the same as the pristine compounds.

Single Crystal X-ray Diffraction: Crystals of CeHaVIO₄ (Ha=Cl, Br; VI=Mo, W) were manually picked up under an optical microscope and mounted to the Rigaku XtaLAB Synergy-I instrument. The data collection was performed at 290 (5) K. The data collection and integration were done by CrysAlis^{Pro} Software (Agilent Technologies, XRD Products; CrysAlis Pro; Agilent Technologies, Inc). The structural solution and refinement were done with Jana2006 ⁴⁷. Details of the data collection and structure refinement are provided in Table 1. Atomic coordinates and selected bond distances are listed in Tables S1 and S2. Crystallographic data for CeHaVIO₄ (Ha=Cl, Br; VI=Mo, W) have been deposited to the Cambridge Crystallographic Data Centre, CCDC, 12 Union Road, Cambridge CB21EZ, UK. Copies of the data can be obtained free of charge by quoting the depository numbers CCDC- 2302882 (CeClMoO₄), CCDC- 2302884 (CeClWO₄), CCDC-2302881 (CeBrMoO₄), and CCDC-2302883 (CeBrWO₄).

Lab powder X-ray Diffraction: Powder X-ray diffraction data were collected at room temperature using a Rigaku Mini Flex 6G diffractometer with Cu-K α radiation (λ =1.5406 Å) in the range $2\theta = 10^{\circ} - 80^{\circ}$, at a scan step of 0.04° with ten seconds exposure time.

UV-Vis Measurements: Diffuse-reflectance spectra were recorded at room temperature by a PERSEE-T8DCS UV-Vis spectrophotometer equipped with an integration sphere in the wavelength range of 230–850 nm. The reflectance data, R, were recorded and converted to the Kubelka-Munk function, $f(R)=(1-R)^2(2R)^{-1}$. Tauc plots, $(KM*E)^2$ and $(KM*E)^{1/2}$, were applied to estimate direct and indirect bandgaps, respectively.

Second Harmonic Generation Measurements: Using the Kurtz and Perry method,⁴⁸ powder SHG responses of CeHaVIO₄ (Ha=Cl, Br; VI=Mo, W) compounds were investigated by a Q-switch laser (2.09 μm, 3 Hz, 50 ns) with various particle sizes, including 38.5–54, 54–88, 88–105, 105–150, and 150–200 μm.. Polycrystalline lab-synthesized AgGaS₂ (AGS) was also sieved into similar particle sizes for SHG efficiency comparison. A short pass filter was placed in front of the photomultiplier tube to prevent scattered 1064 nm photons from being detected.

Table 1. Refined crystallographic parameters of CeClMoO₄, CeClWO₄, CeBrMoO₄, and CeBrWO₄ from single crystal X-ray diffraction.

Compound	CeClMoO4	CeClWO ₄	CeBrMoO4	CeBrWO ₄
Formula	335.5	423.4	380	467.9
weight				
Crystal color	translucent	translucent light	translucent	translucent
	light orange	yellow	yellow	orange
Temperature	296.97	297.6(7)	296.36	296.4
(K)				
Radiation,	Mo-Ka, 0.71073 Å			
wavelength				
Crystal	Monoclinic			
system				
Space group	P1c1 (No. 7)			
a(Å)	9.55135(6)	19.6059(2)	9.77746(9)	9.87827(7)
b(Å)	5.79301(5)	5.89450(10)	5.82090(5)	5.92232(3)
c(Å)	7.94951(9)	7.80090(10)	8.03217(7)	7.93937(5)
β (°)	90.0140(7)	101.4746(8)	90.0106(7)	90.0083(6)
$V(Å^3)$	439.851(7)	883.51(2)	457.143(11)	464.473(11)
${f Z}$	4	8	4	4
Dc (g cm ⁻¹)	5.0665	6.3665	5.5207	6.6907
μ (mm ⁻¹)	13.557	36.679	21.201	42.913
F(000)	596	1448	668	796
Flack	0.292(16)	0.269(12)	0.033(18)	0.266(15)
Parameter				
R_1 , wR_2 (all	0.0138, 0.0182	0.0229, 0.0294	0.0157, 0.0193	0.0211, 0.0256
data)				
R_1 , wR_2 ($I >$	0.0136, 0.0181	0.0257, 0.0298	0.0157, 0.0194	0.0208, 0.0255
2σ(I))				

 $R_1 = \sum ||F_o| - |F_c|| / \sum |F_o|$; $wR_2 = \sum [w(F_o^2 - F_c^2)^2] / \sum [w(F_o^2)^2] / \sum [$

DFT Calculations: The electronic structures of CeHaVIO₄ (Ha=Cl, Br; VI=Mo, W) compounds, including their density of states (DOS) and electronic band structures, were calculated using Vienna Ab-initio Simulation Package. The Perdew–Burke–Ernzerhof (PBE) functional within the generalized gradient approximation (GGA) ⁵³ was adopted to calculate the exchange-correlation potential, with an energy cutoff of 400 eV. The numerical integration of the Brillouin

zone was performed using a Monkhorst–Pack k-point sampling.⁵⁴ For CeBrMoO₄, CeBrWO₄, and CeClMoO₄, the k-point mesh is $5 \times 9 \times 7$. For CeClWO₄, with a larger unit cell, the k-point mesh is $3 \times 7 \times 5$. Pseudopotentials generated with the projector augmented-wave (PAW) method were employed.⁵⁵ To treat the highly correlated Ce 4f electrons, an on-site repulsion Hubbard parameter, U = 4 eV, was used.⁵⁶

Photocurrent response measurement. Crystals of CeHaVIO₄ (Ha=Cl, Br; VI=Mo, W) are very stable in air. Hence, crystals of CeHaVIO₄ (Ha=Cl, Br; VI=Mo, W) were manually crushed and grounded in mortar in air. Ethanol was employed to aid in forming suspension solutions. The suspension solution was slowly dropped on the ITO glass to form a uniform film. The uniformness of the prepared films was checked by an optical microscope. The films were dried at 393K under vacuum for 2 hours. The photocurrent performance of the photoanode was evaluated in a traditional three-electrode configuration, consisting of CeHaVIO₄ (Ha=Cl, Br; VI=Mo, W) photoanodes as the working electrode, platinum wire as the counter electrode, and Ag/AgCl as the reference electrode. 1M Na₂SO₄ aqueous solution was used as the electrolyte. Linear sweep voltammetry and I-t scans were collected on the electrochemical workstation (Gamry Interface 5000) under illumination of AM 1.5 (1 sun, 100 mW/cm²) using a solar simulator (Newport).

Results and discussions

Crystal growth and phase purification

Prior to this work, CeClMoO₄ ⁵⁷⁻⁵⁹ and CeBrMoO₄ ⁶⁰ were reported. The high temperature solid-state method was employed to grow the crystals of CeClMoO₄ ⁵⁷⁻⁵⁹ and CeBrMoO₄ ⁶⁰. CeClMoO₄ ⁶⁰ was found as a phase-pure sample while significant amounts of impurity existed in CeBrMoO₄ ⁶⁰ samples. The previous work did not address crystal growth. In this work, we employed salt flux pairs of CeCl₃/NaCl and CeBr₃/NaBr to grow CeClMoO₄ and CeBrMoO₄, respectively. Millimeter-sized crystals of CeClMoO₄ and CeBrMoO₄ were collected after salt flux was removed by DI water as shown in **Figure S1**. The phase purity of CeClMoO₄ and CeBrMoO₄ was verified by PXRD as shown in **Figure S2** and **Figure S3**, respectively. Two new tungsten-contained compounds, CeClWO₄ and CeBrWO₄, were grown by salt flux as single-phase large crystals (**Figures S1, S4**, and **S5**). A combination of various halides would be a good flux for the crystal growth of oxyhalides ³².

Crystal Structure

CeHaVIO₄ (Ha=Cl, Br; VI=Mo, W) belongs to the REHaVIO₄ (RE=Y, La-Lu, Ha=Cl, Br; VI=Mo, W) family ⁵⁷⁻⁶⁵, which exhibits abundant structural chemistry (vide infra). Two structure types were found within CeHaVIO₄ compounds. CeClMoO₄ is isostructural to CeBrMoO₄ and CeBrWO₄. CeClWO₄ crystallizes in its own structure type. CeClMoO₄ was reported by Dorhout, P.K. et al in 2010, which crystallizes in centrosymmetric monoclinic space group $P2_1/c$ (no. 14) with unit cell parameters of a = 19.1228(18) Å, b = 5.7992(5) Å, and c = 7.9591(7) Å, and $\beta =$ 90.037(6)° 57. Our single crystal X-ray diffraction indicated that CeClMoO₄ forms in the acentric monoclinic space Pc7) group with unit cell parameters of a = 9.5513(1) Å, b = 5.793(1) Å, and c =7.9495(1) Å, and $\beta = 90.014(1)^{\circ}$, which was also verified by SHG measurements (vide infra). CeBrMoO₄ is isostructural to CeClMoO₄, which was confirmed by our experimental results and a previous study ⁶⁰. CeBrWO₄ is a new compound, which was never reported. Like CeBrMoO₄ and CeClMoO₄, CeBrWO₄ is also isotypic to LaBrWO₄ ³² and crystallizes in the acentric monoclinic space group Pc (no.7) with unit cell parameters of a = 9.8783(1) Å, b = 5.9223(1) Å, and c =7.9394(1) Å, and $\beta = 90.008(1)^{\circ}$.

The β angles of all these structures are very close to 90°, making them pseudo-orthorhombic. However, orthorhombic symmetry was precluded because we tested orthorhombic space groups and they all result in much higher R-values and significant residual electron peaks and holes. Due to the pseudo-orthorhombic acentric symmetry, the twinning laws for inversion and 180° rotation along a-axis were both considered in our structural refinement.

To simplify the discussion, CeBrWO₄ is selected to present the structure of CeBrMoO₄ and CeClMoO₄. The Wyckoff sequence of CeBrWO₄ is a^{14} with the Pearson symbol mP28. There are two distinct Ce atoms, two distinct W atoms, two distinct Br atoms, and eight distinct O atoms in the asymmetric unit cell of CeBrWO₄ with full occupancy. The crystal structure of CeBrWO₄ is summarized in **Figures 1a and 1b**. CeBrWO₄ forms a three-dimensional (3D) framework, which is constructed by two-dimensional (2D) [CeBrO₄]⁶⁻ strips and one-dimensional (1D) [WO₅] strands. The 1D [WO₅] strands are constructed by distorted [WO₅] trigonal bipyramids, which connect to each other via apical oxygen atoms and run along the [001] direction. Five oxygen atoms surround central W atoms with four short interactions of 1.755(7) - 1.842(6) Å and one long

interaction of 2.230(5)-2.239(5) Å. Our previous bonding picture study of LaBrWO₄ revealed the moderately strong interaction of the elongated W-O interactions of 2.24 Å ³². The 2D [CeBrO₄]⁶-strips are built by distorted tetracapped trigonal prisms [CeO₆Br₃], where six oxygen atoms and three bromine atoms surround the central Ce atoms. The Ce-Br interactions fall into the range of 3.1393(16) - 3.257(2) Å, which is similar to many compounds that include Ce-Br interactions such as, CeBr₃ (3.108-3.158 Å) ⁶⁶, CeBrMoO₄(3.112-3.227 Å) ⁶⁰, Ce₃(SiS₄)₂Br(3.101-3.328 Å) ⁶⁷, etc. The Ce-O interactions are within the range of 2.473(8)-2.697(9) Å of CeBrWO₄, which are comparable to many oxides such as K₆Ce₂(SO₄)₆(2.498-2.648 Å) ⁶⁸, CeBrMoO₄(2.466-2.726 Å) ⁶⁰, CeCu₃Co₄O₁₂ (2.486 Å) ⁶⁹, CeMoBO₆ (2.427-2.619 Å) ⁷⁰, etc.

CeClWO₄ is a new compound, which crystallizes in a new structure type. CeClWO₄ adopts a different unit cell: a = 19.6059(2) Å, b = 5.89450(10) Å, and c = 7.80090(10) Å, and $\beta =$ 101.4746(8)°, which is a 2× supercell structure of the other three title compounds with the transformation matrix being (2 0 $\frac{1}{2}$, 0 1 0, 0 0 1). This can be demonstrated by comparing the (h1l) reciprocal lattice planes (Figure S6). The refined structure is also in the acentric monoclinic Pc (no. 7) space group. The details of refinement are included in **Table 1**. The acentric structure nature of CeClWO₄ was also verified by second harmonic generation measurements (vide infra). Interestingly, our refined unit cell parameters of CeClWO₄ are comparable to those of the $P2_1/c$ CeClMoO₄ structure reported by Dorhout, except for the β angle (101.5° vs 90.0°). ⁵⁷ The Wyckoff sequence of CeClWO₄ is a^{28} with the Pearson symbol mP56. There are four distinct Ce atoms, four distinct W atoms, four distinct Cl atoms, and sixteen distinct O atoms in the asymmetric unit cell of CeClWO₄ with full occupancy. The crystal structure of CeClWO₄ is exhibited in Figures 1b and 1c. The 3D crystal structure of CeClWO₄ is similar to 3D CeBrWO₄ with doubling the [100] axis. The 3D framework of CeClWO₄ is constructed by 2D [CeClO₄]⁶⁻ strips and 1D [WO₅] strands. The 2D [CeClO₄]⁶⁻ strips are made by distorted tetracapped trigonal prisms [CeO₆Cl₃] via sharing vertices and edges. The 1D [WO₅] strands within CeClWO₄ are constructed by distorted [WO₅] trigonal bipyramids, which were also found within CeBrWO₄. The W-O interactions within CeClWO₄ are 1.730(9) Å-2.190(9) Å, which is comparable with W-O interactions of CeBrWO₄ (1.755(7) Å - 2.239(5) Å).

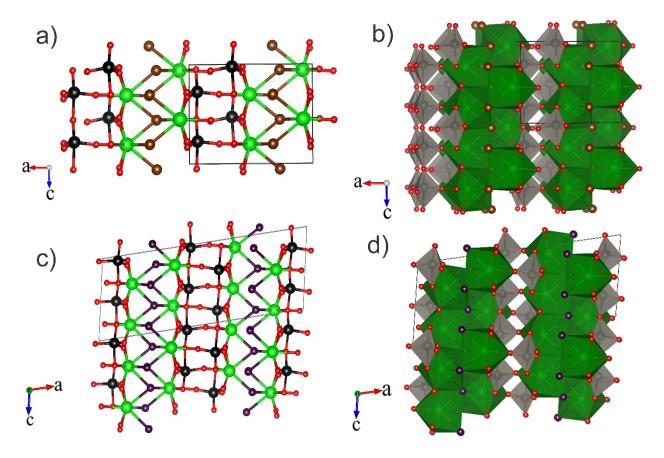


Figure 1. (a) Ball-stick structure and (b) polyhedral structure of CeBrWO₄ viewed along the [010] direction. (c) Ball-stick structure and (d) polyhedral structure of CeClWO₄ viewed along the [010] direction. Ce: green, W: black, O: red, Br: brown, and Cl: purple.

REHaVIO₄ (RE=Y, La-Lu, Ha=Cl, Br; VI=Mo, W) family exhibits very rich structure chemistry. Prior to this work, seven structure types were reported for the REHaVIO₄ (RE=Y, La-Lu, Ha=Cl, Br; VI=Mo, W) family, which is summarized in **Table S3** ⁵⁷⁻⁶⁵. The comparison of physical properties such as magnetic properties, bandgaps, and photoluminescent properties between CeHaVIO₄ and the compounds of REHaVIO₄ (RE=Y, La-Lu, Ha=Cl, Br; VI=Mo, W) family were summarized in Table S3. This work of CeClWO₄ adds the eighth structure type to the REHaVIO₄ (RE=Y, La-Lu, Ha=Cl, Br; VI=Mo, W) family. Compared to their differences, these structures exhibit more similarity. 3D framework structure constructed by [REO_xHa_y] polyhedra and [VIO_z]_{z=4 or 5} units is a common feature for the REHaVIO₄ (RE=Y, La-Lu, Ha=Cl, Br; VI=Mo, W) family. The 1D [VIO₅]_{VI=Mo or W} strands were also discovered within CeClMoO₄ (space group *P2*₁/*c*) structure type ⁵⁷, LaClWO₄(space group *Pbc2*₁) structure type ⁶¹, and LaClWO₄ (space group *Pmcn*) structure type ⁶¹. The discrepancies between structures reported for the same

compound, such as Dorhout's CeClMoO₄ in *P2*₁/*c vs.* this work's CeClMoO₄ in *Pc*, is likely due to polymorphism – a given REHaVIO₄ compound may adopt similar but different crystal structures, especially when prepared with different synthetic methods. For example, LaClWO₄ crystallizes in acentric orthorhombic Pbc2₁ and centrosymmetric orthorhombic Pmcn space group ⁶⁰. In our own study of LaHaVIO₄ and CeHaVIO₄, we found crystals whose diffraction patterns indicate much larger unit cells or even exhibit diffused scattering, which suggests the possible intergrowth between different polymorph structures. We are devoting more efforts into these challenging crystals in hope to provide more insights into the abundant structural chemistry in the REHaVIO₄ (RE=Y, La-Lu, Ha=Cl, Br; VI=Mo, W) family, which accounts for their broad applications such as photoluminescent applications, ⁶² NLO applications, ³² and the photocurrent response in this work.

Linear Optical properties

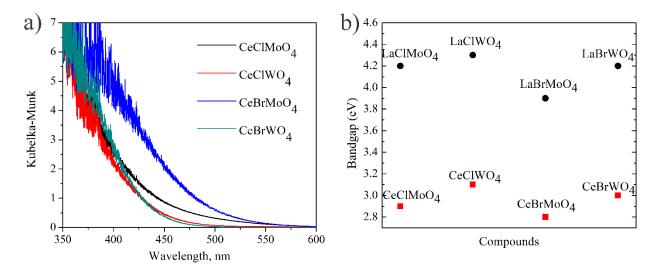


Figure 2. (a) Kubelka-Munk diffuse reflectance solid-state UV-Vis spectra of CeHaVIO₄ (Ha=Cl, Br; VI=Mo, W). (b) The comparison of bandgaps between CeHaVIO₄ (Ha=Cl, Br; VI=Mo, W) and LaHaVIO₄ (Ha=Cl, Br; VI=Mo, W) compounds.

The optical bandgaps of CeHaVIO₄ (Ha=Cl, Br; VI=Mo, W) were estimated by UV-Vis spectrum measurements (**Figure 2a**). CeClWO₄ is similar to CeBrWO₄, which exhibits a transition around 450nm. Based on electronic structure calculation, CeHaVIO₄ are direct-bandgap semiconductors (*vide infra*). The direct allowed transitions of CeHaVIO₄ were calculated by the Tauc plots, which were shown in **Figure 2b**. The calculated direct bandgap of CeClWO₄ and CeBrWO₄ are 3.1(1)

eV and 3.0(1) eV, respectively. There is a transition around 500 nm observed for CeClMoO₄, which results in the calculated direct bandgap of 2.9(1) eV. The CeBrMoO₄ possesses the smallest bandgap of 2.8(1) eV, which originates from its transition around 575 nm. Compared with the isostructural counterparts LaHaVIO₄ (Ha=Cl, Br; VI=Mo, W), the bandgaps of CeHaVIO₄ compounds are much smaller (Figure 2b). The suppression of bandgaps of CeHaVIO₄ compounds originate from the partially filled 4f orbitals of Ce atoms (vide infra). The bandgap suppression also agreed well with the physical appearance of crystals of REHaVIO₄ (RE=La, Ce; Ha=Cl, Br; VI=Mo, W), where LaHaVIO₄ and CeHaVIO₄ compounds are colorless and colorful ³², respectively. Tuning the bandgap of inorganic solids is crucial for many applications such as second harmonic generation ²⁵ and photovoltaics ⁷¹. Our attempts to tune the bandgap of CeHaVIO₄ via replacing Ce with La was found to be effective. As shown in Figures S7-S10, (La_{0.5}Ce_{0.5})ClMoO₄, (La_{0.5}Ce_{0.5})ClWO₄, (La_{0.5}Ce_{0.5})BrMoO₄, and (La_{0.5}Ce_{0.5})BrWO₄ were found to be single phase samples. The bandgap of (La_{0.5}Ce_{0.5}) ClMoO₄, (La_{0.5}Ce_{0.5})ClWO₄, (La_{0.5}Ce_{0.5})BrMoO₄, and (La_{0.5}Ce_{0.5})BrWO₄ were estimated by UV-Vis measurements to be 3.8(1) eV, 3.5(1) eV, 3.6(1) eV, and 3.9(1) eV, respectively. As shown in Figure S11, the bandgap of (La_{0.5}Ce_{0.5})HaVIO₄ (Ha=Cl, Br; VI=Mo, W) samples reside between CeHaVIO₄ and LaHaVIO₄ samples. Mixing La and Ce would be a good strategy to tune their bandgaps. The narrowed bandgaps of CeHaVIO₄ compounds result in good transmission in the IR range. The infrared spectrum of CeHaVIO₄ compounds are shown in Figures S12 and S13. There were no intrinsic vibrational absorption chemical bonds in the wavelength of 2.5-18.2 µm for all CeHaVIO₄ compounds. CeClWO₄ and CeBrWO₄ exhibited comparable IR spectra with three absorption peaks detected around 550 cm⁻¹, which agree well with LaBrWO₄ ³². The strong absorption peaks around 550 cm⁻¹ can be assigned to the v(W-O) vibrations ³². The IR spectrum of CeClMoO₄ is comparable to CeBrMoO₄ with two strong absorption peaks detected around 550 cm⁻¹, which originate from the v(Mo-O) vibrations ³². A comparable IR spectrum was also found in LaBrMoO₄ 32

Electronic Structures

LaHaVIO₄ (Ha=Cl, Br, VI=Mo, W) is isostructural to CeHaVIO₄ (Ha=Cl, Br, VI=Mo, W), except CeClWO₄. It would be interesting to investigate why there are significant bandgap differences

between them. Hence, we employed DFT calculations to study the electronic structures of CeHaVIO₄ (Figures 3, S14-S18).

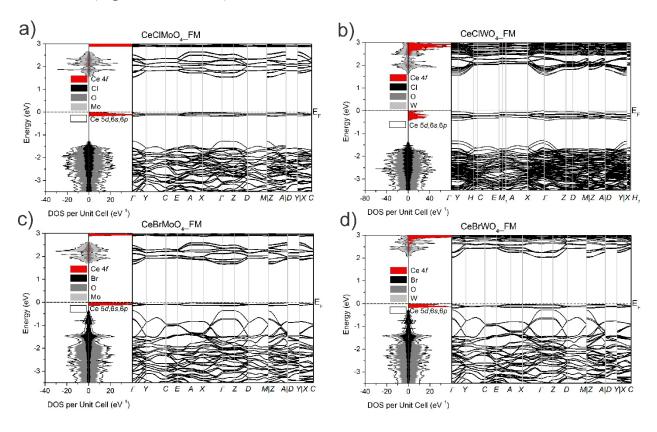


Figure 3. The DOS curves and electronic band structures of CeHaVIO₄ (Ha=Cl, Br, VI=Mo, W).

Using the structures from single crystal refinement, we calculated the DOS and electronic band structures of CeClMoO₄, CeClWO₄, CeBrMoO₄, and CeBrWO₄. Due to the strong correlation of Ce 4f electrons, the Hubbard parameter (U = 4 eV) had to be employed. Otherwise, the self-consistent calculations do not converge. Formally, the valence of Ce is +3, which means each Ce atom has one 4f electron and thus 1 μ B local moment. Because there are multiple Ce atoms in a unit cell, we tried both ferromagnetic and antiferromagnetic ordering of Ce atoms' local moments as well. **Figure 3** lists the DOS and band structures from ferromagnetic calculations of the four compounds. The antiferromagnetic results are shown in **Figure S15-18** in Supporting Information. From both sets of results, we can draw the same conclusions below.

The most prominent feature among all these CeHaVIO₄ compounds is their highly localized Ce 4*f* states. They form a narrow peak in the DOS and very flat bands in the band structures. Moreover, it represents the valence band edges in all cases. For comparison, we also calculated the electronic

structure for LaBrWO₄, which is also shown in **Figure S14**. La has no 4*f* electron in LaHaVIO₄. As a result, the La 4*f* states are absent in DOS and band structure. The valence band edge is mainly contributed by Br states. This comparison clearly explains the band gap differences between CeHaVIO₄ and LaHaVIO₄ – Ce's 4*f* states significantly reduce the band gap of CeHaVIO₄. The calculated bandgaps for CeHaVIO₄ (Ha=Cl, Br, VI=Mo, W) are around 2 eV, which are smaller than experimentally estimated values. The underestimation of bandgaps of inorganic solids is common for DFT calculations ⁷². DFT calculations confirmed the semiconducting nature of CeHaVIO₄, which was also verified by UV-Vis measurements. The charge-balanced formula (Ce ³⁺)(Ha⁻)(VI⁶⁺) (O²⁻)₄ can be established by assigning a formal charge of 3+ to the Ce atoms, 6+ to the Mo and W atoms,1- to the Cl and Br atoms, and 2- to the O atoms. Bond valence sum calculations found the BVS of Ce atoms and W atoms to be 2.98 and 5.95 receptivity for CeClWO₄, which suggests Ce atoms and W atoms with oxidation 3+ and 6+, respectively ²⁴.

Nonlinear Optical properties

The nonlinear optical properties of CeHaVIO₄ (Ha=Cl, Br, VI=Mo, W) were measured and presented in Figure 4. All samples exhibited SHG response under 2090 nm incident lasers, which confirmed the acentric nature of CeHaVIO₄ samples. CeBrMoO₄ and CeBrWO₄ own comparable SHG responses of 0.58× AGS and 0.46× AGS, respectively for samples of 225 µm particle. The SHG intensity of CeBrMoO₄ and CeBrWO₄ increases with increasing particle size, which indicates that CeBrMoO₄ and CeBrWO₄ are type-I phase-matching materials. CeClWO₄ exhibited a much lower SHG response of 0.22× AGS for a sample of 225 µm particle. CeClMoO₄ possessed the lowest SHG response of 0.06× AGS for samples of 225 µm particle. CeClMoO₄ and CeClWO₄ are not type-I phase-matching materials, and the SHG intensity of CeBrMoO₄ and CeBrWO₄ decreases as the particle size increases (Figure 4). The isostructural nature and comparable bandgaps between CeBrMoO₄, CeBrWO₄, and CeClMoO₄ result in distinct SHG responses. CeClMoO₄ and CeClWO₄ are non-phase-matching materials compared to CeBrMoO₄ and CeBrWO₄. Many factors such as the crystal quality or different crystal structures would significantly affect NLO properties ⁷³. The future planned study will be focused on measurements of the birefringence of CeHaVIO₄ to understand this difference. The higher degree distortion of 1D [VIO₅]_{VI=Mo or W} strands plays an important role in enhancing SHG within CeBrMoO₄ and CeBrWO4, which was also observed for LaBrWO₄ compared to LaBrMoO₄ ³².

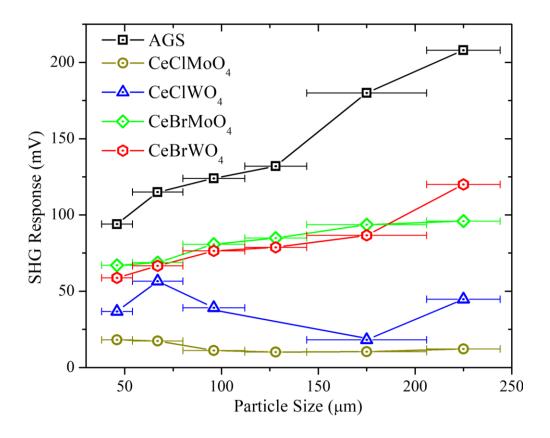


Figure 4. Size-dependent SHG intensities of CeHaVIO₄ (Ha=Cl, Br, VI=Mo, W) samples and the AgGaS₂ (AGS) reference.

Photocurrent response

The bandgaps of CeHaVIO₄ fall into the range of 2.8(1)-3.1(1) eV, which originates from the presence of partially filled 4*f* orbitals of cerium. These partially filled 4*f* orbitals populate between the valance band and conduction band. CeHaVIO₄ crystals can absorb visible light due to their small bandgap nature (**Figure 2a**). The capability of absorption of visible lights coupled with excellent ambient stability contributed to us exploring the photocurrent response of CeHaVIO₄ samples. A material that can generate high photocurrent density under light radiation can be used for photovoltaics to reduce our dependence on fossil energy ^{24, 28}. The photocurrent response of CeHaVIO₄ samples are presented in **Figure 5**. As shown in **Figure 5**, CeHaVIO₄ samples exhibit good photocurrent response. The reproducibility of the photocurrent response of CeHaVIO₄ samples were tested by measuring three samples of each specimen, which are summarized in **Figures S19-S22**. All CeHaVIO₄ samples exhibited good reproducibility. CeClMoO₄ and CeClWO₄ exhibited comparable photocurrent responses of 332 nA Cm⁻² and 369 nA Cm⁻²,

respectively. The photocurrent density of CeBrMoO₄ was 263 nA Cm⁻². CeBrWO₄ possessed the lowest photocurrent response of 138 nA Cm⁻². The photocurrents of CeHaVIO₄ samples slightly decrease after a few cycles, which was observed in many photocurrent-responding materials and originates from the photocorrosion of photoanodes ^{24, 28}. A comparison of photocurrent response among CeHaVIO₄ and many previously reported sulfides and oxyhalides are tabulated in Table S4 ⁷⁴⁻⁸⁹. CeHaVIO₄ exhibit comparable or better photocurrent response than many compounds such as $Eu_3Gd_6MgS_2B_{20}O_{41}$ (0.12 μ A/cm²) ⁷⁸, $Sr_6Cd_2Sb_6S_{10}O_7$ (0.065 μ A/cm²) ⁷⁷, $BaCuSbS_3$ (0.055 $\mu A/cm^2$) ⁷⁶, BaCuSbSe₃ (0.03 $\mu A/cm^2$) ⁷⁶, RbIn₄S₆Cl (0.029 $\mu A/cm^2$) ⁷⁵, Pb₅Sn₃S₁₀Cl₂ (0.019µA/cm²) ⁷⁵, Rb₂Ba₃Cu₂Sb₂S₁₀ (0.006µA/cm²) ⁷⁴. Photocurrent measurements can be useful to extract more intrinsic properties of inorganic solids. An external quantum efficiency (EQE) measurement can be employed to determine the bandgaps of CeHaVIO₄ 90, which are undergoing. CeHaVIO₄ system exhibits both good NLO properties and photocurrent response, which indicates that they are good multifunctional materials. There might exist more new compounds in the REHaVIO₄(RE=La-Lu, Ha=Cl, Br, VI=Mo, W) system, which may uncover more multifunctional materials. The discovery of new heteroanionic compounds usually results in exciting physical properties such as recent works of $C(NH_2)_3BF_4$ and $Ca_2B_3O_6X$ (X = Cl and Br) 92 .

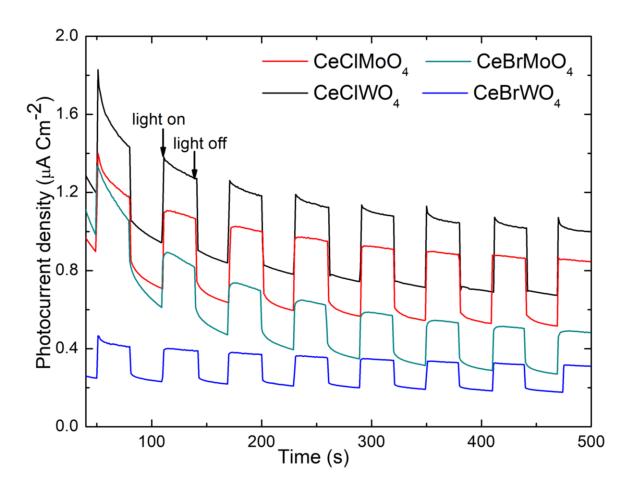


Figure 5. Photocurrent density of CeHaVIO₄ (Ha=Cl, Br, VI=Mo, W) photoanodes over time.

Conclusions

Millimeter-sized crystals of four heteroanionic oxyhalides, CeClMoO4, CeBrMoO4, CeClWO4, and CeBrWO4, had been grown by a halide salt flux method, which are stable in ambient air for a long time. CeClMoO4, CeBrMoO4, CeClWO4, and CeBrWO4 were studied as multifunctional materials, which combine good second harmonic generation (SHG) response and photocurrent signals. Two structure types were found for the CeHaVIO4 (Ha=Cl, Br, VI=Mo, W) system. CeClMoO4 is isostructural to CeBrMoO4 and CeBrWO4, which forms in the LaBrMoO4 structure type. CeClWO4 crystallizes in a new structure type, which adds the eighth structure type to the REHaVIO4 (RE=Y, La-Lu, Ha=Cl, Br; VI=Mo, W) family. The CeHaVIO4 system features a 3D framework, which is made by 2D [REHaO4]⁶⁻ strips and 1D [VIO5] strands. Compared with isostructural LaHaVIO4 system, the bandgaps of CeHaVIO4 system are significantly suppressed from 3.9(1)-4.3(1) eV to 2.8(1)-3.1(1) eV, respectively. The presence of partially filled 4f orbitals

of cerium atoms accounts for the narrower bandgaps of CeHaVIO₄. The CeHaVIO₄ system all exhibited SHG responses. CeBrMoO₄ and CeBrWO₄ are both type-I phase-matching materials, which possess moderate SHG response of 0.58× and 0.46× AGS, respectively. CeBrMoO₄ and CeBrWO₄ are good candidates for IR NLO application due to their moderate SHG response, easygrowth of crystals, high ambient stability, and type-I phase-matching behavior. CeHaVIO₄ films can also generate photocurrent response in the range of 138 nA Cm⁻²- 369 nA Cm⁻² upon light radiation. The REHaVIO₄ (RE=Y, La-Lu, Ha=Cl, Br; VI=Mo, W) family owns rich structural chemistry, which has eight structure types. Functionalities such as NLO application, photoluminescent response, and photocurrent response were found within the REHaVIO₄ family, where more multifunctional materials can be grown by halide salt flux methods.

ASSOCIATED CONTENTS

Supporting Information

The refined crystallographic data, crystal structure summary of the REHaVIO₄ (Ha=Cl, Br; RE=La-Lu; VI=Mo, W) system, comparison of photocurrent density, microscope photos of crystals, lab powder X-ray diffraction results, the (h1l) planes, IR spectrum, DOS plots, photocurrent density results.

Acknowledgments

This research was supported by the National Science Foundation (DMR-2316811). F. W acknowledges NSF MRI 2117129 for funding the single crystal X-ray diffractometer. W. W thanks the support by U.S. Department of Energy's Office of Energy Efficiency and Renewable Energy (EERE) under the Solar Energy Technologies Office Award Number DE-EE0009525. The views expressed herein do not necessarily represent the views of the U.S. Department of Energy or the United States Government. Z. J thanks Yangjinyi Wang's help on plotting TOC figure.

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Notes

The authors declare no competing financial interest.

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